

## 1200V SIC MOSFETS

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### Features

- High-power capability: 1200V MOSFET with SiC technology
- Fast, reliable switching
- Enhanced performance
- Wide on-resistance selection: ranging from 21mΩ to 120mΩ (typ.)
- Efficiency: Superior thermal properties and low switching losses
- Durability: Avalanche ruggedness
- Versatility: TO247 3-pin and 4-pin package options



Our MOSFETs are available in 3-pin and 4-in (Kelvin source) configurations and meet the rising demand for high-power, highvoltage applications.

Boasting exceptional on-resistance values from  $21m\Omega$  to  $120m\Omega$  (typ.) and fast switching speeds.







UPS and Data Centers

# MCC Amplifies Performance with 1200V SiC MOSFETs in TO-247 Packages

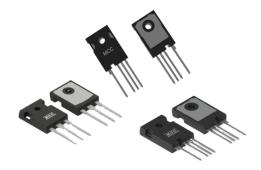


# Leveraging Efficiency, Ruggedness & Design Flexibility

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## Experience Unmatched Efficiency and Ruggedness in Power Solutions



## **Product Attributes, Parametrics & Datasheets**

Product	Туре	Package	Drain-Source Voltage(VDS)	Continuous Drain Current(ID)	Typ. Drain- Source On- Resistance RDS(ON)	Mounting Type	Datasheet
<u>SICW040N120H4</u>	SIC MOSFET	TO-247-4	1200V	62A	40mΩ	Through-Hole	<u>Info</u>
<u>SICW040N120H</u>	SIC MOSFET	TO-247AB	1200V	62A	40mΩ	Through-Hole	<u>Info</u>
<u>SICW080N120H4</u>	SIC MOSFET	TO-247-4	1200V	33A	80m <b>Ω</b>	Through-Hole	<u>Info</u>
<u>SICW021N120P4</u>	SIC MOSFET	TO-247-4L	1200V	100A	21mΩ	Through-Hole	<u>Info</u>
<u>SICW080N120H</u>	SIC MOSFET	TO-247AB	1200V	33A	80m <b>Ω</b>	Through-Hole	<u>Info</u>
SICW021N120P	SIC MOSFET	TO-247AB	1200V	100A	21mΩ	Through-Hole	<u>Info</u>
<u>SICW025N120H4</u>	SIC MOSFET	TO-247-4	1200V	86A	25mΩ	Through-Hole	<u>Info</u>
<u>SICW120N120H4</u>	SIC MOSFET	TO-247-4	1200V	24A	120mΩ	Through-Hole	<u>Info</u>
<u>SICW025N120H</u>	SIC MOSFET	TO-247AB	1200V	86A	25mΩ	Through-Hole	<u>Info</u>
<u>SICW120N120H</u>	SIC MOSFET	TO-247AB	1200V	24A	120mΩ	Through-Hole	<u>Info</u>

## CONTACT MCC TO REQUEST A SAMPLE

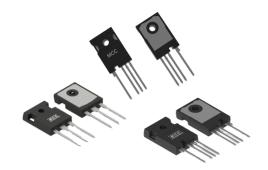


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**1200V SiC MOSFETs** 



# Versatile 1200V SiC MOSFETs: Designed for Demanding Applications



MCC Semi's new 1200V SiC MOSFETs are designed to ensure top performance and reliability in demanding environments.

## **Applications:**



## Industrial

- Motor drives
- Welding equipment
- Power supplies
- Renewable energy systems
  Uninterruptible power

Energy

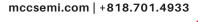
• Charging infrastructure

#### **UPS and Data Centers**

 Uninterruptible power supply (UPS) systems

Cloud systems





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